STATUS

PENDING

ABANDONED



NON-PROVISIONAL

APPLICATION NO.

DECLARATION FOR NON-PROVISIONAL PATENT APPLICATION

As a below named inventor, I hereby declare that:

My residence, post office address and citizenship are as stated below at 201 et seq. beneath my name.

I believe I am the original, first and sole inventor if only one name is listed at 201 below, or an original, first and joint inventor if plural names are listed at 201 et seq. below, of the subject matter which is claimed and for which a patent is sought on the invention entitled

METHOD AND APPARATUS FOR ADJUSTING THE THICKNESS OF A THIN LAYER OF SEMICONDUCTOR MATERIAL

and for which a patent application			(if annlinghla)
was filed in the United States	on as Application No.	D	(ij applicable) (declaration not
accompanying application) v	with amendment(s) filed on	·	(if applicable)
was filed as PCT international	al Application No.	on	and was amended
under PCT Article 19 on			_ (if applicable)
I hereby state that I have revie amended by any amendment refe		nts of the above identified appli	cation, including the claims, a
I acknowledge the duty to disclo Regulations, § 1.56.	se information known to me to	be material to patentability as def	ined in Title 37, Code of Federa
	v and have also identified below	tates Code, § 119(a)-(d) of any for any foreign application for pater aimed:	
EARLIEST FOREIGN API	PLICATION(S), IF ANY, FILE	D PRIOR TO THE FILING DAT	E OF THE APPLICATION
APPLICATION NUMBER	COUNTRY	DATE OF FILING (day, month, year)	PRIORITY CLAIMED
0210208	France	August 12, 2002	⊠ YES □ NO
0210209	France	August 12, 2002	☑ YES ☐ NO
I hereby claim the benefit under below.	er Title 35, United States Code	e, § 119(e) of any United States	provisional application(s) liste
PROVISIONAL APPLICATION NUMBER		FILING	G DATE
as the subject matter of each of provided by the first paragraph me which is material to patental	the claims of this application is of Title 35, United States Code pility as defined in Title 37, Cod	120 of any United States application not disclosed in the prior United § 112, I acknowledge the duty the of Federal Regulations, § 1.56 ternational filing date of this applications.	States application in the manne o disclose information known to which became available between

FILING DATE

PATENTED

^{*} for use only when the application is assigned to a company, partnership or other organization.

I hereby declare that all statements made herein of my own knowledge are true and that all statements made on information and belief are believed to be true; and further that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment, or both, under Section 1001 of Title 18 of the United States Code and that such willful false statements may jeopardize the validity of the application or any patent issuing thereon.

FULL NAME OF	LAST NAME	FIRST NAME	MIDDLE NAMÉ	
INVENTOR	GHYSELEN	L		
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FILL NAME OF	LAST NAME	FIRST NAME	MIDDLE NAME	
INVENTOR	OSTERNAUD	Bénédite		
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	SIGNATURE OF INVENTOR 203		DATE	
	otenand		VV [0,	3103
	INVENTOR RESIDENCE & CITIZENSHIP POST OFFICE ADDRESS FULL NAME OF INVENTOR RESIDENCE & CITIZENSHIP POST OFFICE ADDRESS FULL NAME OF INVENTOR RESIDENCE & CITIZENSHIP POST OFFICE	INVENTOR RESIDENCE & CITY Seyssinet-Pariset STREET POST OFFICE ADDRESS FULL NAME OF INVENTOR RESIDENCE & CITY Grenoble STREET 3 Place des Tilleuls FULL NAME OF INVENTOR POST OFFICE ADDRESS FULL NAME OF INVENTOR POST OFFICE ADDRESS FULL NAME OF INVENTOR CITY Grenoble STREET 3 Place des Tilleuls CITY CITY CITY CITY CITY CITY CITY CIT	RESIDENCE & CITY STATE OR FOREIGN COUNTRY Seyssinet-Pariset POST OFFICE ADDRESS SIGNATURE OF LAST NAME AULNETTE RESIDENCE & CITY STATE OR FOREIGN COUNTRY FIRST NAME CITIZENSHIP POST OFFICE ADDRESS FULL NAME OF INVENTOR RESIDENCE & CITY STATE OR FOREIGN COUNTRY France CITY STATE OR FOREIGN COUNTRY France CITY STATE OR FOREIGN COUNTRY France CITY Grenoble POST OFFICE ADDRESS SIGNATURE OF INVENTOR 202 FULL NAME OF INVENTOR 202 SIGNATURE OF INVENTOR 203	INVENTOR RESIDENCE & CITY RESIDENCE & CITY POST OFFICE ADDRESS SIGNATURE OF LAURENT VIRAVAUX SIGNATURE OF LAURENT VIRAVAUX FULL NAME OF INVENTOR RESIDENCE & CITY STATE OR COUNTRY FRANCE FIRST NAME CÓCILE AULNETTE CÓCILE STATE OR COUNTRY FRANCE FIRST NAME CITY STATE OR COUNTRY FRANCE CITY STATE OR FOREIGN COUNTRY France France STATE OR COUNTRY France France France France FOR 1 2 3 FULL NAME OF INVENTOR 202 DATE OR 1 2 3 FULL NAME OF INVENTOR 202 FULL NAME OF INVENTOR 203 FULL NAME OF INVENTOR 203

In re Application of: Bruno GHYSELEN et al.

Application No.:

Group Art Unit:

Filing Date: August 6, 2003

Examiner:

For:

METHOD AND APPARATUS

Attorney Docket No.: 4717-6400

FOR ADJUSTING THE THICKNESS

OF A LAYER OF SEMICONDUCTOR MATERIAL

POWER OF ATTORNEY BY ASSIGNEE AND EXCLUSION OF INVENTOR(S) UNDER 37 C.F.R. 3.71

Commissioner for Patents P.O. Box 1450 Alexandria, Virginia 22313-1450

Sir:

The undersigned assignee of the entire interest in the above-identified subject application hereby appoints Allan A. Fanucci (Reg. No. 30,256) and Daniel J. Hulseberg (Reg. No. 36,554) of WINSTON & STRAWN (Customer No. 28765) to prosecute this application and to transact all business in the United States Patent and Trademark Office connected therewith.

Please direct all correspondence for this application to Customer No. 28765 to the attention of Allan A. Fanucci (telephone 212-294-3311, facsimile 212-294-4700).

An assignment of the entire interest in the above-identified subject application is submitted herewith for recording and a copy is attached. The undersigned has reviewed this assignment and, to the best of his knowledge, title is in the assignee seeking to take action in this application and that he is empowered to act on its behalf.

ASSIGNEE:

S.O.I. TEC SILICON ON INSULATOR TECHNOLOGIES S.A.

Signature:	Shew
Date of Signature:	Ser 11th & 3
Typed Name:	Emmanuel HUYGHE
Position/Title:	IP MANAGER
Address:	Parc Technologique de Fontains
	38586 Bernin
	FRANCE

ASSIGNMENT

WHEREAS, each of,

Bruno GHYSELEN, a citizen of France, residing at 58 rue George Maeder, 38170 Seyssinet-Pariset, France;

Cécile AULNETTE, a citizen of France, residing at 3 Place des Tilleuls, 38000 Grenoble, France; and

Bénédite OSTERNAUD, a citizen of France, residing at 26 rue Lieutenant Fiancey, 38120 Saint Egreve, France.

ASSIGNOR, is an inventor of the invention in METHOD AND APPARATUS FOR ADJUSTING THE THICKNESS OF A THIN LAYER OF SEMICONDUCTOR MATERIAL, for which a United States patent application is identified by Winston & Strawn Docket No. 4717-6400and

	is being filed concurrently with the recordation of this Assignment.	
\boxtimes	was filed on August 6, 2003 as Application No	

WHEREAS, S.O.I. TEC SILICON ON INSULATOR TECHNOLOGIES S.A., a French corporate body having a place of business at Parc Technologique des Fontaines, F-38190 Bernin, France, ASSIGNEE, is desirous of obtaining my entire right, title and interest in, to and under the said invention and the said application.

NOW, THEREFORE, in consideration of the sum of One Dollar (\$1.00) to each inventor in hand paid, and other good and valuable consideration, the receipt of which is hereby acknowledged, each ASSIGNOR, has sold, assigned, transferred and set over, and by these presents do hereby sell, assign, transfer and set over, unto the said ASSIGNEE, its successors, legal representatives and assigns, his or her right, title and interest in, to and under the said invention, and the said United States provisional application and the said invention in all applications claiming priority thereto under 35 U.S.C. § 119(e) or converted therefrom, and all divisions, renewals and continuations thereof, and all Patents of the United States which may be granted thereon and all reissues and extensions thereof;

And each ASSIGNOR hereby authorizes and requests the Commissioner of Patents and Trademarks of the United States, and any Official of any country or countries foreign to the United States, whose duty it is to issue patents or other evidence or forms of industrial property protection on applications as aforesaid, to issue the same to the said ASSIGNEE, its successors, legal representatives and assigns, in accordance with the terms of this instrument;

And each ASSIGNOR hereby covenants and agrees that they have full right to convey the entire interest herein assigned, and that they have not executed, and will not execute, any agreement in conflict herewith;

And each ASSIGNOR further covenants and agrees that they will communicate to the said ASSIGNEE, its successors, legal representatives and assigns, any facts known to them respecting said invention, and testify in any legal proceeding, sign all lawful papers, execute all divisional, continuing, reissue and foreign applications, make all rightful oaths, and generally do everything possible to aid the said ASSIGNEE or, its successors, legal representatives and assigns, to obtain and enforce proper protection for said invention in all countries;

And each ASSIGNOR hereby authorizes the ASSIGNEE's patent attorney to complete this form by the addition of the application number, application filing date, and attorney docket number, if necessary.

In witness whereof, each inventor has affixed his or her signature.

Date_S	eck 11th	, 2003			7
		.1			Bruno GHYSELEN
On Witness, a name, who and deed.	ppeared Brosigned the	uno Ghyselen,	2003, before me, to me known and ument, and ackno	d known to moveledged the s	to be the person of that same to be his/her free act
				<i>.</i> Λ.	

Witness

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Date <u>08/29/03</u> , 2003	Antos
,	Cécile AULNETTE
On Accept 2003, before me, Witness, appeared Cécile AULNETTE, to me known that name, who signed the foregoing instrument, and free act and deed.	and known to me to be the person of acknowledged the same to be his/her
	• •
Witness	· Me
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Date Aucor Egth, 2003	e Le vincond
Date ~ 0 (8.) 1 29 , 2003	Cécile AULNETTE
	Benedite @ISTERNAUD
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On Avor 2, 2003, before me, Witness, appeared Cécile AULNETTE, to me known	E HUYGHE
witness, appeared Cécile AULNETTE, to me known that name, who signed the foregoing instrument, and free act and deed. B. OSTERNAUD	and known to me to be the person of acknowledged the same to be his/her
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Witness	Mear
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